30V 90A N-Channel Enhancement Mode Power MOSFET

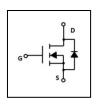
Features

- RDSON \leq 3m Ω @Vgs=10V
- · Advanced trench technology
- \bullet Excellent $R_{\text{DS(ON)}} and \ Low \ Gate \ Charge$
- · Lead free product is acquired

Application

- Load Switch
- PWM Application
- Power management

SYMBOL







PDFN5*6

ASSEMBLY MESSAGE

Product Name	Package	Packaging		
BXT030N03C	PDFN5*6	Reel		

ABSOLUTE MAXIMUM RATINGS (Tc=25°C unless otherwise noted)

Parameter		Symbol	Rating PDFN5*6	Unit	
Drain-Source Voltage		V _{DSS}	30	V	
Drain Current	Conf	inuous (T _C = 25°C)	I-	90	А
	Conf	inuous (T _C = 100°C)	- I _D	59	Α
Drain Current	Pulsed (Note1)		I _{DM}	360	А
Single Pulsed Avalanche Energy		Avalanche Energy		306	mJ
Gate-Source Voltage		-Source Voltage		±20	V
Power Dissipation T _C =25°C		wer Dissipation T _C =25°C		44.6	W
Maximum Junction Temperature		num Junction Temperature		150	°C
Storage Temperature Range		TstG	-55 to 175	°C	

Note: 1. Repetitive Rating: Pulse width limited by maximum junction temperature

THERMAL CHARACTERISTICS

Parameter	Symbol	Max.	Unit	
Farameter	Syllibol	PDFN5*6		
Thermal Resistance, Junction to Case Reuc		2.8	°C/W	



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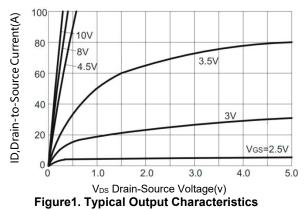
ELECTRICAL CHARACTERISTICS ($T_J=25^{\circ}C$,unless otherwise Noted)

Parameter	Symbol	Test Condition	Min.	Тур.	Max.	Unit
OFF CHARACTERISTICS					•	
Drain-Source Breakdown Voltage	BV _{DSS}	VGS=0V, ID=250µA	30			V
Zero Gate Voltage Drain Current	IDSS	VDS=30V, VGS=0V			1	uA
Gate-Body Leakage Current, Forward		VGS=20V			100	nA
Gate-Body Leakage Current, Reverse	Igss	VGS=-20V			-100	nA
ON CHARACTERISTICS						
Gate Threshold Voltage	V _{GS(TH)}	VDS=VGS, ID=250μA	1	1.5	2.5	V
Davis Course On Ot 1 D 11		VGS=10V, ID=30A		2.5	3	mΩ
Drain-Source On-State Resistance	R _{DS(ON)}	VGS=4.5V, ID=20A		4.4	6.5	mΩ
DYNAMIC PARAMETERS						
Input Capacitance	Ciss			3489		pF
Output Capacitance	Coss	VDS=15V, VGS=0V, f=1.0MHz		401		pF
Reverse Transfer Capacitance	Crss	I= I.UIVIHZ		390		pF
SWITCHING PARAMETERS						
Turn-ON Delay Time	t _{D(ON)}			12		ns
Turn-ON Rise Time	t _R	VDD=15V, ID=60A, VGS		89		ns
Turn-OFF Delay Time	t _{D(OFF)}	= 10V, RG=1.8Ω		35		ns
Turn-OFF Fall-Time	t _F			60		ns
Total Gate Charge(Note2)	Q_{G}	\/DC -45\/ \/CC -40\/		66		nC
Gate Source Charge	Q _{GS}	VDS =15V, VGS =10V, ID=15A		10		nC
Gate Drain Charge	Q _{GD}			16		nC
SOURCE- DRAIN DIODE RATINGS	AND CHAR	ACTERISTICS				
Drain-Source Diode Forward Voltage	V _{SD}	Is=20A, VGS=0V			1.2	V
Diode Continuous Forward Current	ls				90	Α
Maximum Pulsed Drain to Source Diode Forward Current	Іѕм				360	Α

Note: 2. Essentially independent of operating temperature



TYPICAL CHARACTERISTICS



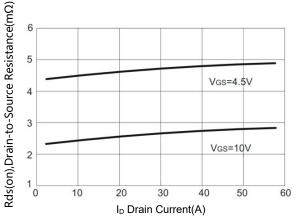


Figure 3. On-Resistance versus Drain Current

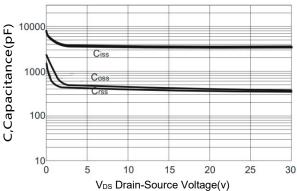


Figure 5. Typical Capacitance versus V_{DS}

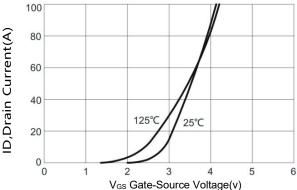


Figure 2. Typical Transfer Characteristics

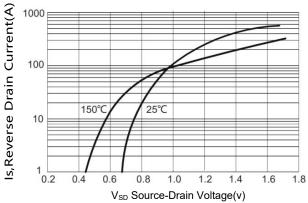


Figure 4. Diode forward voltage versus Current

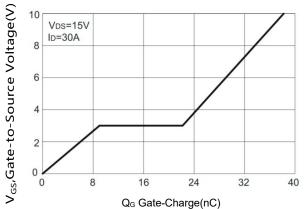


Figure 6. Typical Gate Charge versus V_{GS}

TYPICAL CHARACTERISTICS(Cont.)

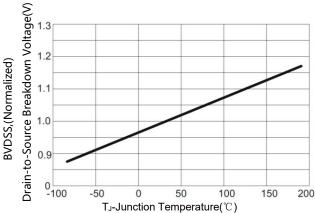


Figure 7. BV_{DSS} Variation with Temperature

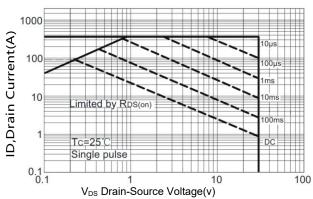


Figure 9. Maximum Safe Operating Area

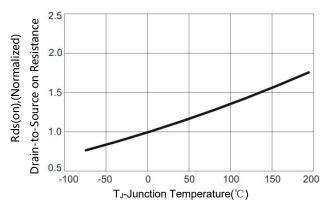


Figure 8. On-Resistance Variation with Temperature

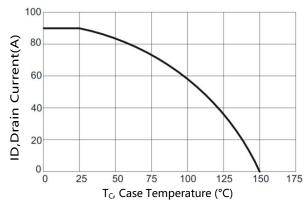
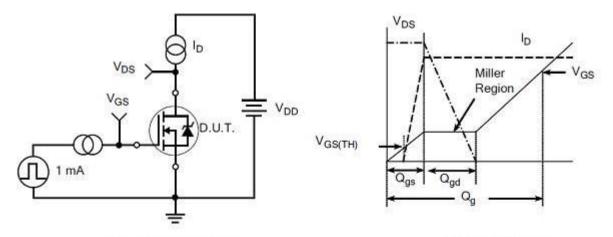
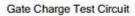


Figure 10. Maximum Continuous Drain Current versus Case Temperature

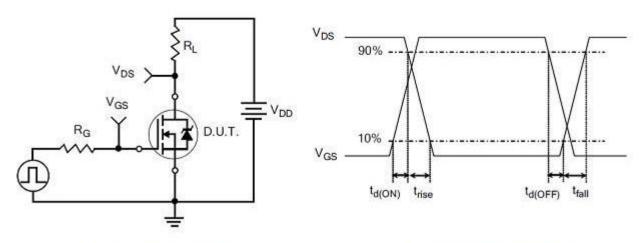


TEST CIRCUITS AND WAVEFORMS





Gate Charge Waveform

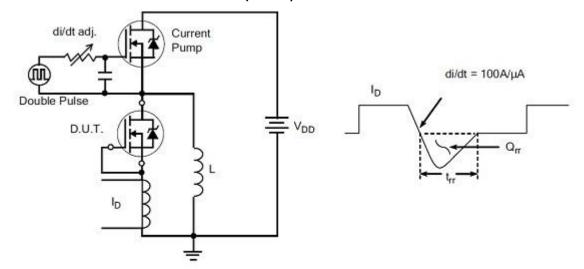


Resistive Switching Test Circuit

Resistive Switching Waveforms

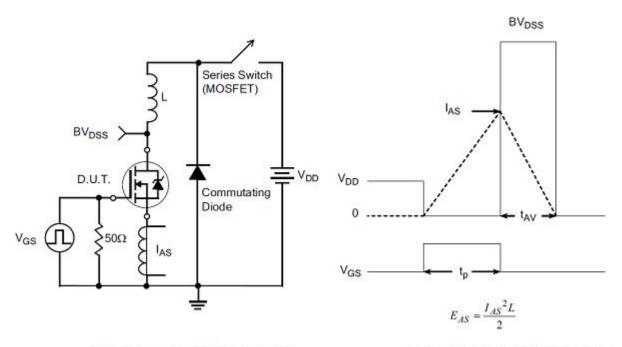


TEST CIRCUITS AND WAVEFORMS(Cont.)



Diode Reverse Recovery Test Circuit

Diode Reverse Recovery Waveform



Unclamped Inductive Switching Test Circuit

Unclamped Inductive Switching Waveforms

Revision history

Document revision history

Date	Revision	Changes
25-Nov-2021	1.0	First release

Version: 1.0

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